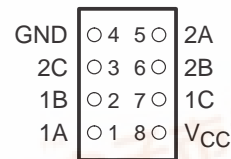


- Available in the Texas Instruments NanoStar™ and NanoFree™ Packages
- Operates at 0.8 V to 2.7 V
- Sub 1-V Operable
- Max  $t_{pd}$  of 0.5 ns at 1.8 V
- Low Power Consumption, 10  $\mu$ A at 2.7 V
- High On-Off Output Voltage Ratio
- High Degree of Linearity
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

DCT OR DCU PACKAGE  
(TOP VIEW)



YEP OR YZP PACKAGE  
(BOTTOM VIEW)



## description/ordering information

This dual analog switch is operational at 0.8-V to 2.7-V  $V_{CC}$ , but is designed specifically for 1.1-V to 2.7-V  $V_{CC}$  operation.

The SN74AUC2G66 can handle both analog and digital signals. It permits signals with amplitudes of up to 2.7-V (peak) to be transmitted in either direction.

NanoStar™ and NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

## ORDERING INFORMATION

T <sub>A</sub>	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING‡
–40°C to 85°C	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP	Tape and reel	SN74AUC2G66YEPR	___U6_
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Tape and reel	SN74AUC2G66YZPR	
	SSOP – DCT	Tape and reel	SN74AUC2G66DCTR	U66_ _ _
	VSSOP – DCU	Tape and reel	SN74AUC2G66DCUR	U66_ _ _

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

‡ DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site.

DCU: The actual top-side marking has one additional character that designates the assembly/test site.

YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar and NanoFree are trademarks of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

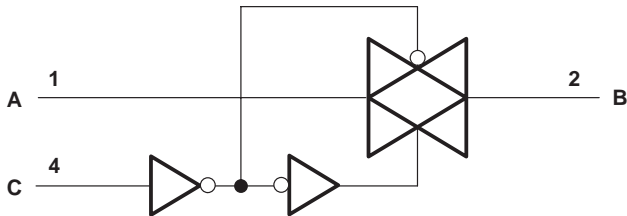
SN74AUC2G66  
DUAL BILATERAL ANALOG SWITCH

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FUNCTION TABLE

CONTROL INPUT (C)	SWITCH
L	OFF
H	ON

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, $V_{CC}$ (see Note 1)	–0.5 V to 3.6 V
Input voltage range, $V_I$ (see Notes 1 and 2)	–0.5 V to 3.6 V
Switch I/O voltage range, $V_{I/O}$ (see Notes 1 and 2)	–0.5 V to $V_{CC} + 0.5$ V
Control input clamp current, $I_{IK}$ ( $V_I < 0$ )	–50 mA
I/O port diode current, $I_{IOK}$ ( $V_{I/O} < 0$ or $V_{I/O} > V_{CC}$ )	±50 mA
On-state switch current, $I_T$ ( $V_{I/O} = 0$ to $V_{CC}$ )	±50 mA
Continuous current through $V_{CC}$ or GND	±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): DCT package	220°C/W
DCU package	227°C/W
YEP/YZP package	102°C/W
Storage temperature range, $T_{stg}$	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltages are with respect to ground unless otherwise specified.
  2. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
  3. The package thermal impedance is calculated in accordance with JESD 51-7.

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## DUAL BILATERAL ANALOG SWITCH

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### recommended operating conditions (see Note 4)

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	0.8	2.7	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.1 V to 1.95 V	0.65 × V <sub>CC</sub>	
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 0.8 V	0	V
		V <sub>CC</sub> = 1.1 V to 1.95 V	0.35 × V <sub>CC</sub>	
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.7	
V <sub>I/O</sub>	I/O port voltage	0	V <sub>CC</sub>	V
V <sub>I</sub>	Control input voltage	0	3.6	V
Δt/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 0.8 V to 1.65 V <sup>†</sup>	20	ns/V
		V <sub>CC</sub> = 1.65 V to 2.3 V <sup>‡</sup>	20	
		V <sub>CC</sub> = 2.3 V to 2.7 V <sup>‡</sup>	20	
T <sub>A</sub>	Operating free-air temperature	–40	85	°C

<sup>†</sup> The data was taken at C<sub>L</sub> = 15 pF, R<sub>L</sub> = 2 kΩ (see Figure 1).

<sup>‡</sup> The data was taken at C<sub>L</sub> = 30 pF, R<sub>L</sub> = 500 Ω (see Figure 1).

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP <sup>§</sup>	MAX	UNIT
r <sub>on</sub>	On-state switch resistance V <sub>I</sub> = V <sub>CC</sub> or GND, V <sub>C</sub> = V <sub>IH</sub> (see Figures 1 and 2)	I <sub>S</sub> = 4 mA	1.1 V	17	40	Ω
			1.65 V	7	20	
		I <sub>S</sub> = 8 mA	2.3 V	4	15	
r <sub>on(p)</sub>	Peak on resistance V <sub>I</sub> = V <sub>CC</sub> to GND, V <sub>C</sub> = V <sub>IH</sub> (see Figures 1 and 2)	I <sub>S</sub> = 4 mA	1.1 V	131	180	Ω
			1.65 V	32	80	
		I <sub>S</sub> = 8 mA	2.3 V	15	20	
Δr <sub>on</sub>	Difference of on-state resistance between switches V <sub>I</sub> = V <sub>CC</sub> to GND, V <sub>C</sub> = V <sub>IH</sub> (see Figures 1 and 2)	I <sub>S</sub> = 4 mA	1.1 V		3	Ω
			1.65 V		1	
		I <sub>S</sub> = 8 mA	2.3 V		1	
I <sub>S(off)</sub>	Off-state switch leakage current V <sub>I</sub> = V <sub>CC</sub> and V <sub>O</sub> = GND, or V <sub>I</sub> = GND and V <sub>O</sub> = V <sub>CC</sub> , V <sub>C</sub> = V <sub>IL</sub> (see Figure 3)	2.7 V		±1		μA
				±0.1 <sup>†</sup>		
I <sub>S(on)</sub>	On-state switch leakage current V <sub>I</sub> = V <sub>CC</sub> or GND, V <sub>C</sub> = V <sub>IH</sub> , V <sub>O</sub> = Open (see Figure 4)	2.7 V		±1		μA
				±0.1 <sup>†</sup>		
I <sub>I</sub>	Control input current V <sub>I</sub> = V <sub>CC</sub> or GND	0 to 2.7 V			±5	μA
I <sub>CC</sub>	Supply current V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	0.8 V to 2.7 V			10	μA
C <sub>ic</sub>	Control input capacitance	2.5 V		2.5		pF
C <sub>io(off)</sub>	Switch input/output capacitance	2.5 V		3		pF
C <sub>io(on)</sub>	Switch input/output capacitance	2.5 V		7		pF

<sup>§</sup> T<sub>A</sub> = 25°C

# SN74AUC2G66

## DUAL BILATERAL ANALOG SWITCH

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**switching characteristics over recommended operating free-air temperature range,  $C_L = 15\text{ pF}$  (unless otherwise noted) (see Figure 5)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 0.8\text{ V}$	$V_{CC} = 1.2\text{ V} \pm 0.1\text{ V}$		$V_{CC} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$			$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
$t_{pd}^\dagger$	A or B	B or A	1		0.6		0.5			0.5		0.4	ns
$t_{en}$	C	A or B	5	0.5	3	0.5	2.1	0.5	0.9	1.6	0.5	1.4	ns
$t_{dis}$	C	A or B	5.3	0.5	4	0.5	3	0.5	2.6	3.3	0.5	2.7	ns

$^\dagger$  The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).

**switching characteristics over recommended operating free-air temperature range,  $C_L = 30\text{ pF}$  (unless otherwise noted) (see Figure 5)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$			$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$		UNIT
			MIN	TYP	MAX	MIN	MAX	
$t_{pd}^\dagger$	A or B	B or A			0.7		0.7	ns
$t_{en}$	C	A or B	0.5	1.6	2.7	0.5	2.3	ns
$t_{dis}$	C	A or B	0.5	2.7	3.4	0.5	2	ns

$^\dagger$  The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).

**analog switch characteristics,  $T_A = 25^\circ\text{C}$**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	$V_{CC}$	TYP	UNIT
Frequency response $^\ddagger$ (switch ON)	A or B	B or A	$C_L = 50\text{ pF}$ , $R_L = 600\ \Omega$ , $f_{in} = \text{sine wave}$ (see Figure 6)	0.8 V	101	MHz
				1.1 V	150	
				1.4 V	175	
				1.65 V	250	
				2.3 V	400	
			$C_L = 5\text{ pF}$ , $R_L = 50\ \Omega$ , $f_{in} = \text{sine wave}$ (see Figure 6)	0.8 V	450	
				1.1 V	>500	
				1.4 V	>500	
				1.65 V	>500	
				2.3 V	>500	
Crosstalk $^\S$ (between switches)	A or B	B or A	$C_L = 50\text{ pF}$ , $R_L = 600\ \Omega$ , $f_{in} = 1\text{ MHz}$ (sine wave) (see Figure 7)	0.8 V	-60	dB
				1.1 V	-60	
				1.4 V	-60	
				1.65 V	-60	
				2.3 V	-60	
			$C_L = 5\text{ pF}$ , $R_L = 50\ \Omega$ , $f_{in} = 1\text{ MHz}$ (sine wave) (see Figure 7)	0.8 V	-65	
				1.1 V	-65	
				1.4 V	-65	
				1.65 V	-65	
				2.3 V	-65	

$^\ddagger$  Adjust  $f_{in}$  voltage to obtain 0 dBm at output. Increase  $f_{in}$  frequency until dB meter reads -3 dB.

$^\S$  Adjust  $f_{in}$  voltage to obtain 0 dBm at input.

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## DUAL BILATERAL ANALOG SWITCH

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### analog switch characteristics, $T_A = 25^\circ\text{C}$ (continued)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	$V_{CC}$	TYP	UNIT
Crosstalk (control input to signal output)	C	A or B	$C_L = 50\text{ pF}$ , $R_L = 600\ \Omega$ , $f_{in} = 1\text{ MHz}$ (square wave) (see Figure 8)	0.8 V	9	mV
				1.1 V	14	
				1.4 V	15	
				1.65 V	16	
				2.3 V	20	
Feed-through attenuation <sup>‡</sup> (switch OFF)	A or B	B or A	$C_L = 50\text{ pF}$ , $R_L = 600\ \Omega$ , $f_{in} = 1\text{ MHz}$ (sine wave) (see Figure 9)	0.8 V	–50	dB
				1.1 V	–50	
				1.4 V	–50	
				1.65 V	–50	
				2.3 V	–50	
			$C_L = 5\text{ pF}$ , $R_L = 50\ \Omega$ , $f_{in} = 1\text{ MHz}$ (sine wave) (see Figure 9)	0.8 V	–60	
				1.1 V	–60	
				1.4 V	–60	
				1.65 V	–60	
				2.3 V	–60	
Sine-wave distortion	A or B	B or A	$C_L = 50\text{ pF}$ , $R_L = 10\text{ k}\Omega$ , $f_{in} = 1\text{ kHz}$ (sine wave) (see Figure 10)	0.8 V	7	%
				1.1 V	0.25 6	
				1.4 V	0.04	
				1.65 V	0.03	
				2.3 V	0.01	
	A or B	B or A	$C_L = 50\text{ pF}$ , $R_L = 10\text{ k}\Omega$ , $f_{in} = 10\text{ kHz}$ (sine wave) (see Figure 10)	0.8 V	3.7	
				1.1 V	0.4	
				1.4 V	0.04	
				1.65 V	0.02	
				2.3 V	0.02	

<sup>‡</sup> Adjust  $f_{in}$  voltage to obtain 0 dBm at input.

### operating characteristics, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	$V_{CC} = 0.8\text{ V}$	$V_{CC} = 1.2\text{ V}$	$V_{CC} = 1.5\text{ V}$	$V_{CC} = 1.8\text{ V}$	$V_{CC} = 2.5\text{ V}$	UNIT
		TYP	TYP	TYP	TYP	TYP	
$C_{pd}$ Power dissipation capacitance	$f = 10\text{ MHz}$	2.5	2.5	2.5	2.5	2.5	pF

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DUAL BILATERAL ANALOG SWITCH

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PARAMETER MEASUREMENT INFORMATION

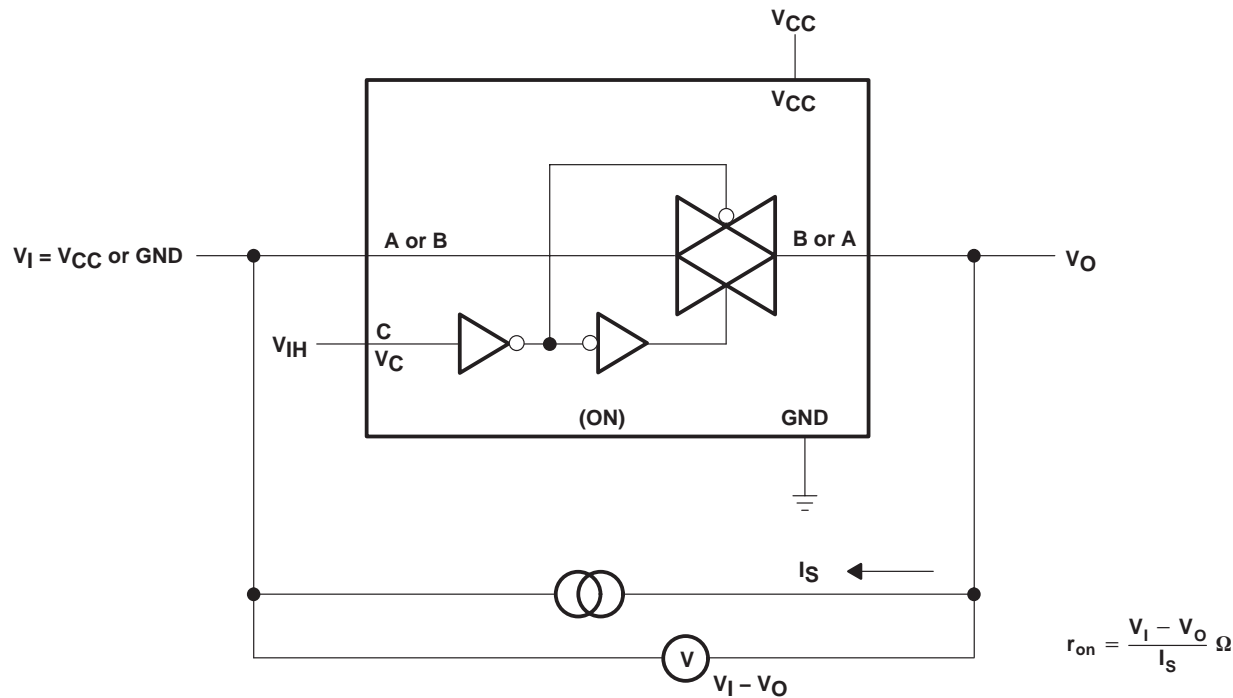


Figure 1. On-State Resistance Test Circuit

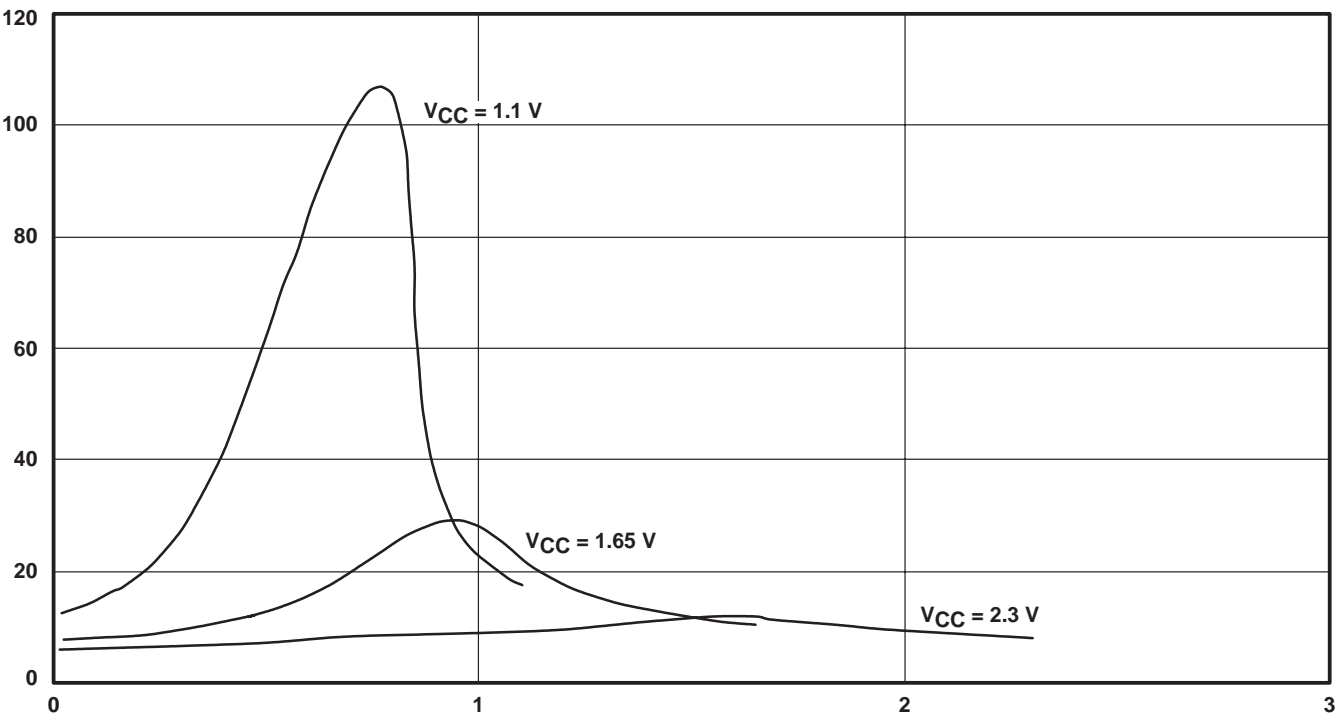


Figure 2. Typical  $r_{on}$  as a Function of Voltage ( $V_I$ ) for  $V_I = 0$  to  $V_{CC}$

PARAMETER MEASUREMENT INFORMATION

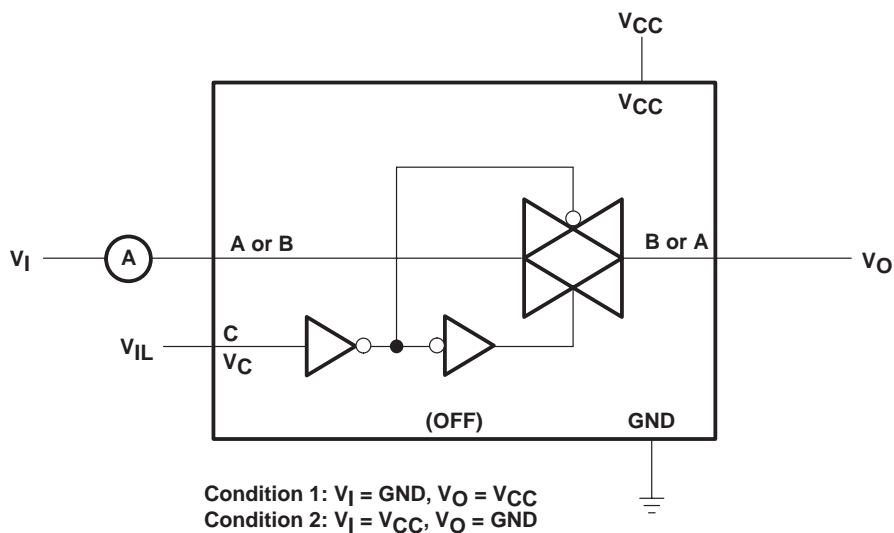


Figure 3. Off-State Switch Leakage-Current Test Circuit

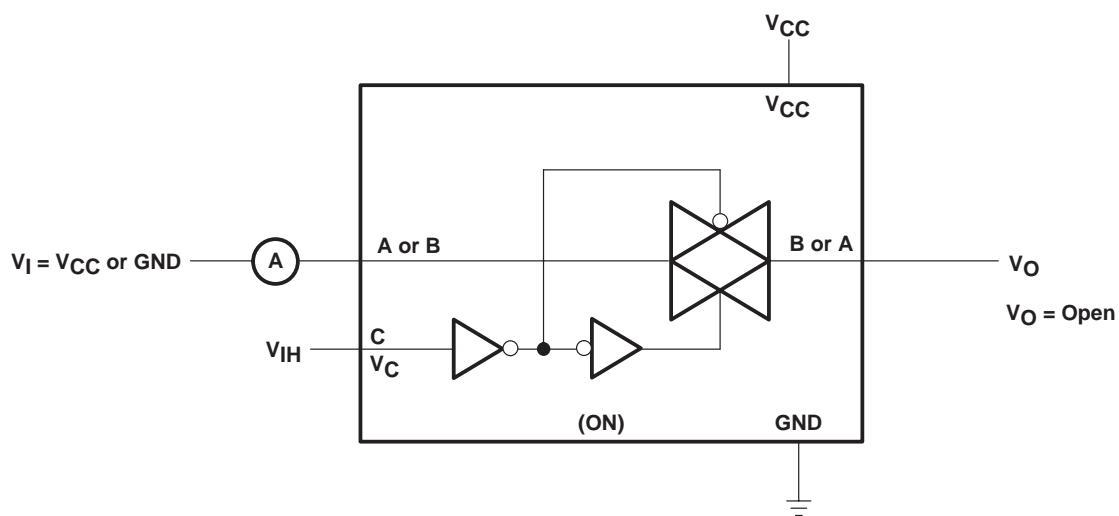


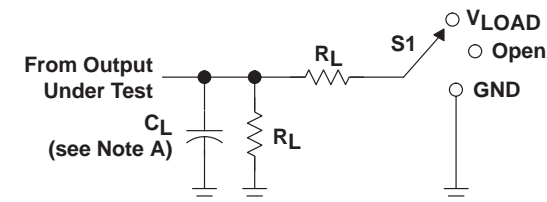
Figure 4. On-State Leakage-Current Test Circuit

# SN74AUC2G66

## DUAL BILATERAL ANALOG SWITCH

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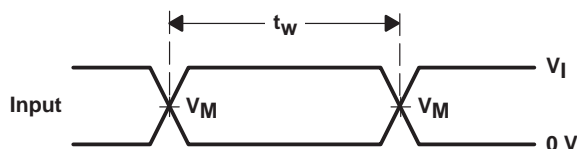
### PARAMETER MEASUREMENT INFORMATION



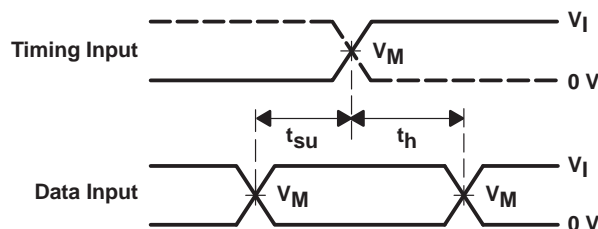
TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND

LOAD CIRCUIT

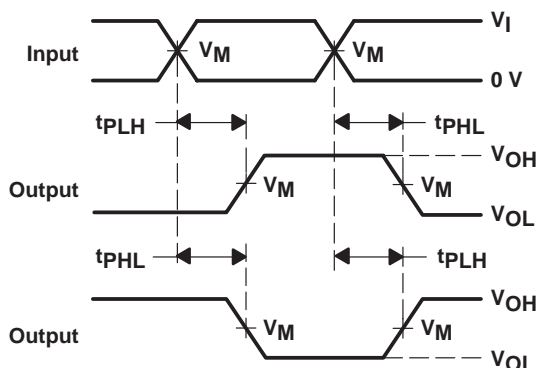
$V_{CC}$	INPUTS		$V_M$	$V_{LOAD}$	$C_L$	$R_L$	$V_{\Delta}$
	$V_I$	$t_r/t_f$					
0.8 V	$V_{CC}$	$\leq 2$ ns	$V_{CC}/2$	$2 \times V_{CC}$	15 pF	2 k $\Omega$	0.1 V
$1.2 \text{ V} \pm 0.1 \text{ V}$	$V_{CC}$	$\leq 2$ ns	$V_{CC}/2$	$2 \times V_{CC}$	15 pF	2 k $\Omega$	0.1 V
$1.5 \text{ V} \pm 0.1 \text{ V}$	$V_{CC}$	$\leq 2$ ns	$V_{CC}/2$	$2 \times V_{CC}$	15 pF	2 k $\Omega$	0.1 V
$1.8 \text{ V} \pm 0.15 \text{ V}$	$V_{CC}$	$\leq 2$ ns	$V_{CC}/2$	$2 \times V_{CC}$	15 pF	2 k $\Omega$	0.15 V
$2.5 \text{ V} \pm 0.2 \text{ V}$	$V_{CC}$	$\leq 2$ ns	$V_{CC}/2$	$2 \times V_{CC}$	15 pF	2 k $\Omega$	0.15 V
$1.8 \text{ V} \pm 0.15 \text{ V}$	$V_{CC}$	$\leq 2$ ns	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	1 k $\Omega$	0.15 V
$2.5 \text{ V} \pm 0.2 \text{ V}$	$V_{CC}$	$\leq 2$ ns	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	500 $\Omega$	0.15 V



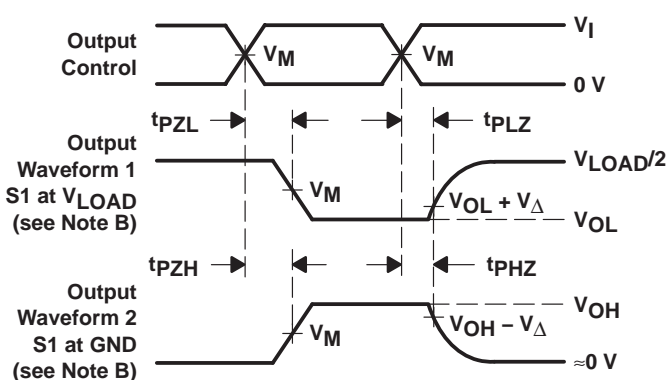
VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES  
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES  
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ , slew rate  $\geq 1 \text{ V/ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - All parameters and waveforms are not applicable to all devices.

Figure 5. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION

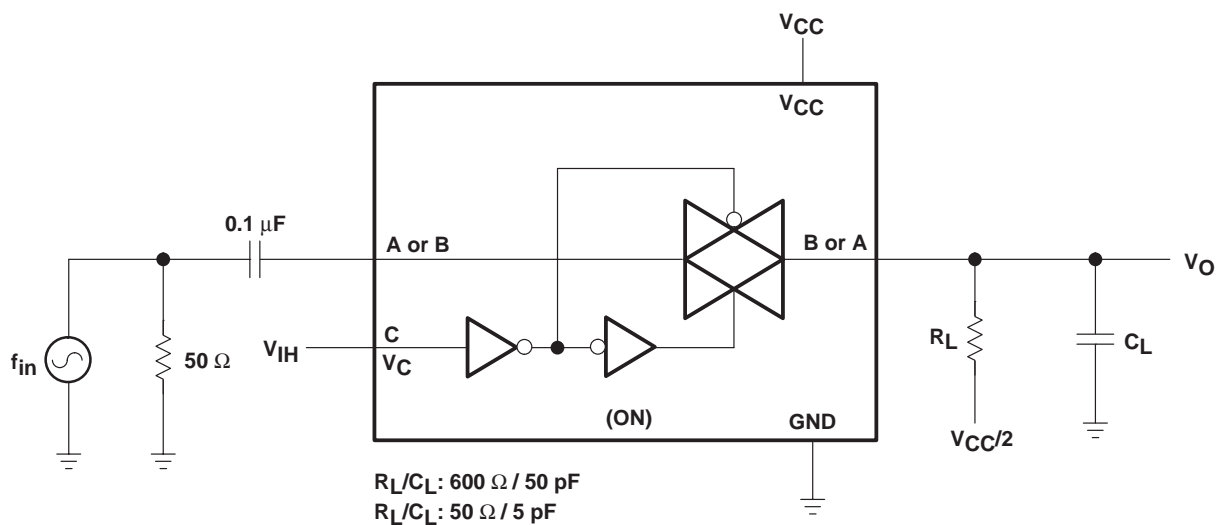


Figure 6. Frequency Response (Switch ON)

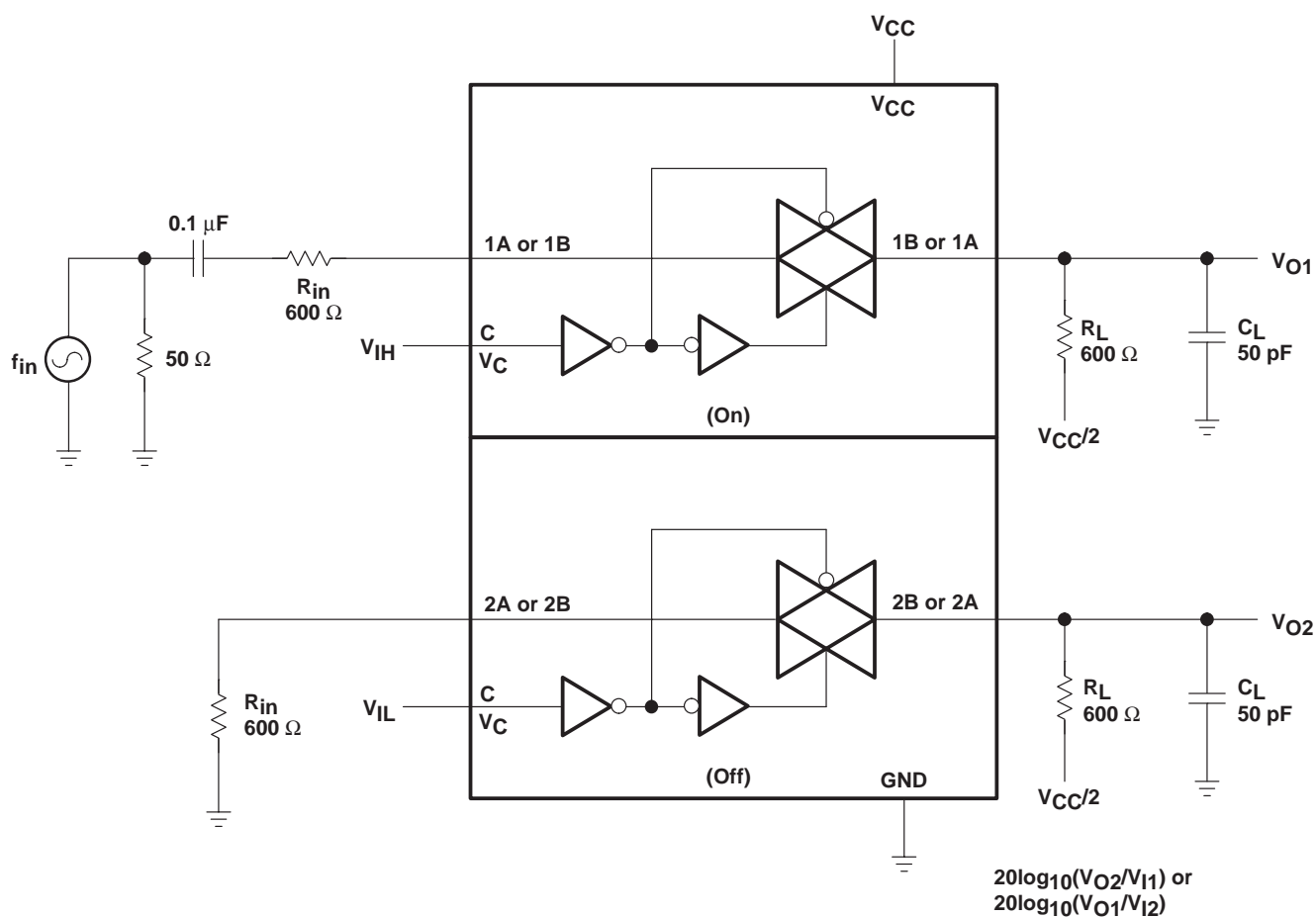
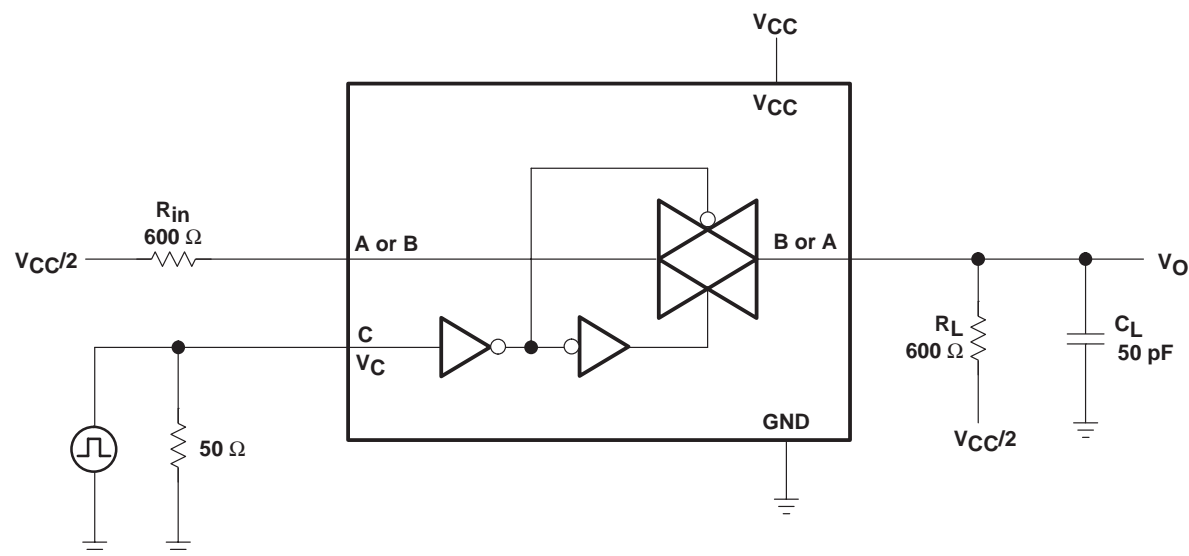


Figure 7. Crosstalk (Between Switches)

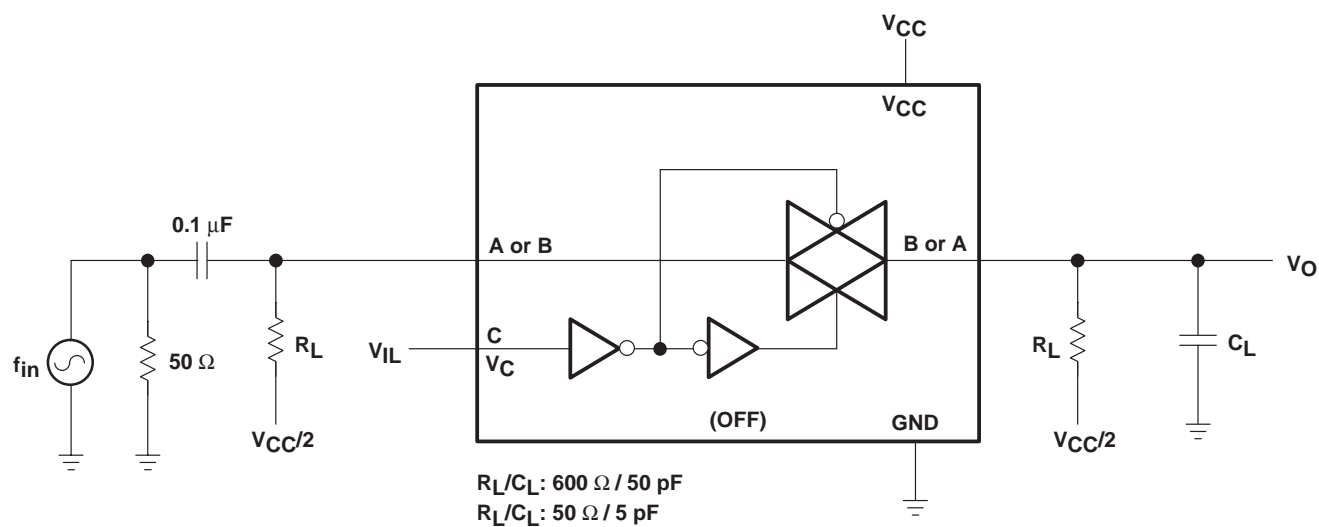
**SN74AUC2G66**  
**DUAL BILATERAL ANALOG SWITCH**

SCES507 – NOVEMBER 2003

**PARAMETER MEASUREMENT INFORMATION**



**Figure 8. Crosstalk (Control Input – Switch Output)**



**Figure 9. Feed Through, Switch Off**

PARAMETER MEASUREMENT INFORMATION

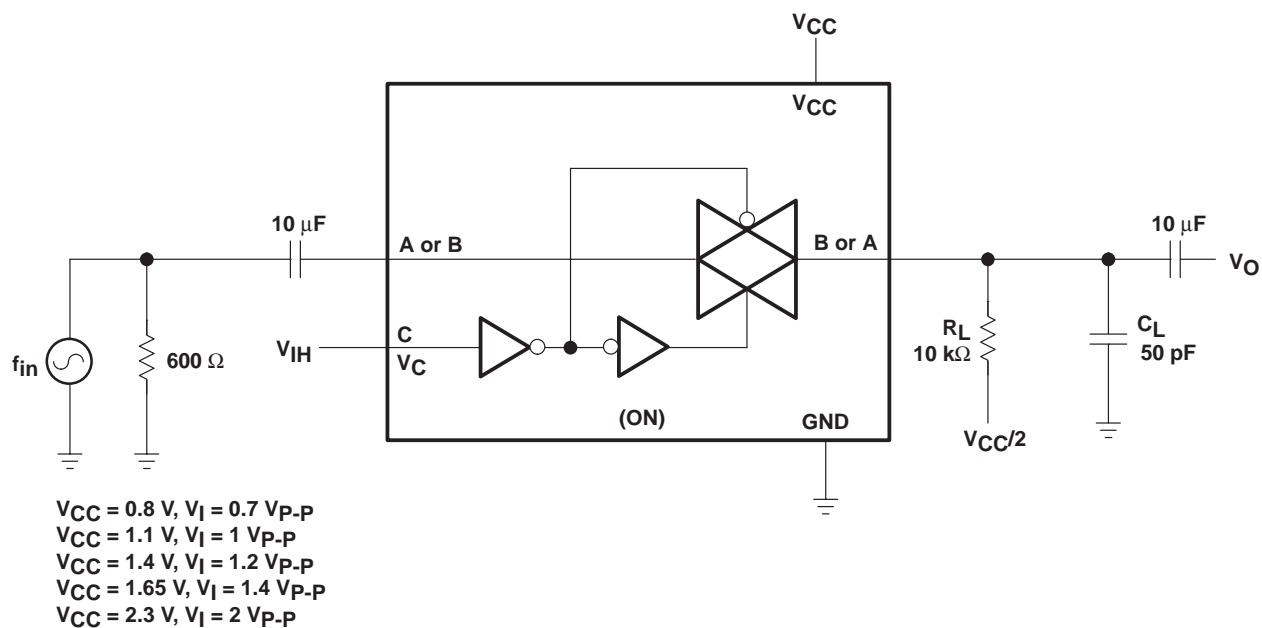


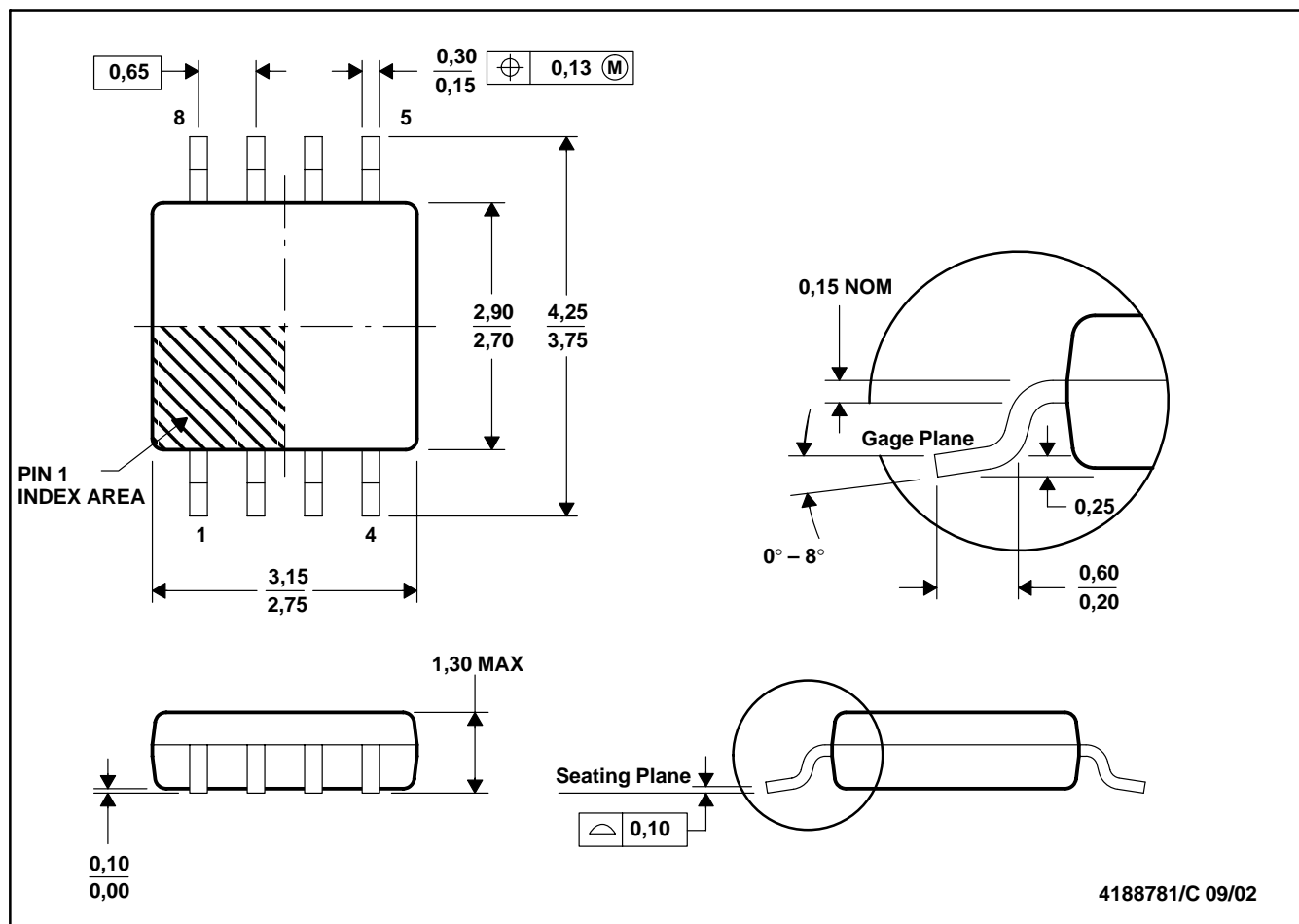
Figure 10. Sine-Wave Distortion

# MECHANICAL DATA

MPDS049B – MAY 1999 – REVISED OCTOBER 2002

DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



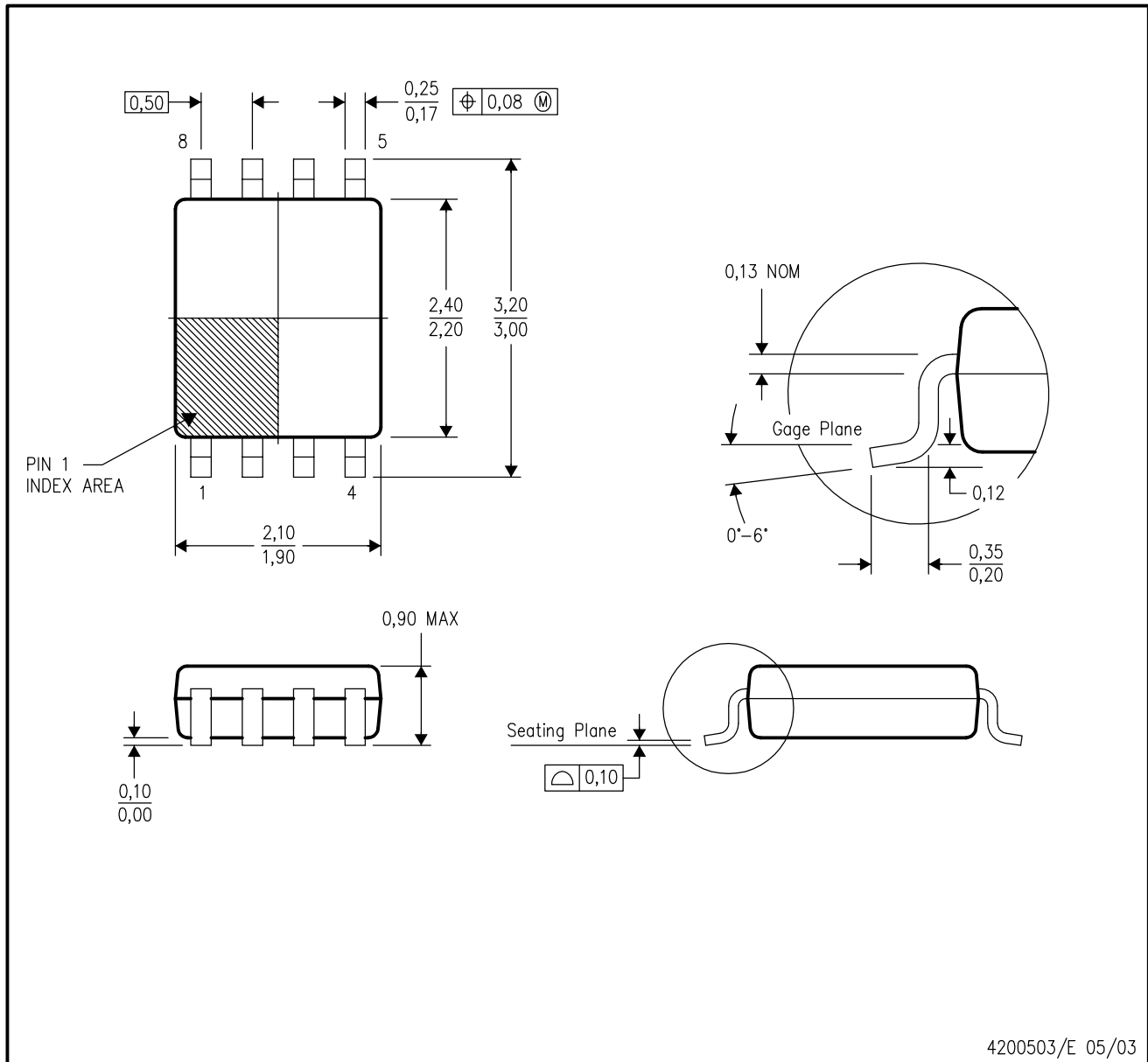
4188781/C 09/02

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion
  - D. Falls within JEDEC MO-187 variation DA.

## MECHANICAL DATA

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)

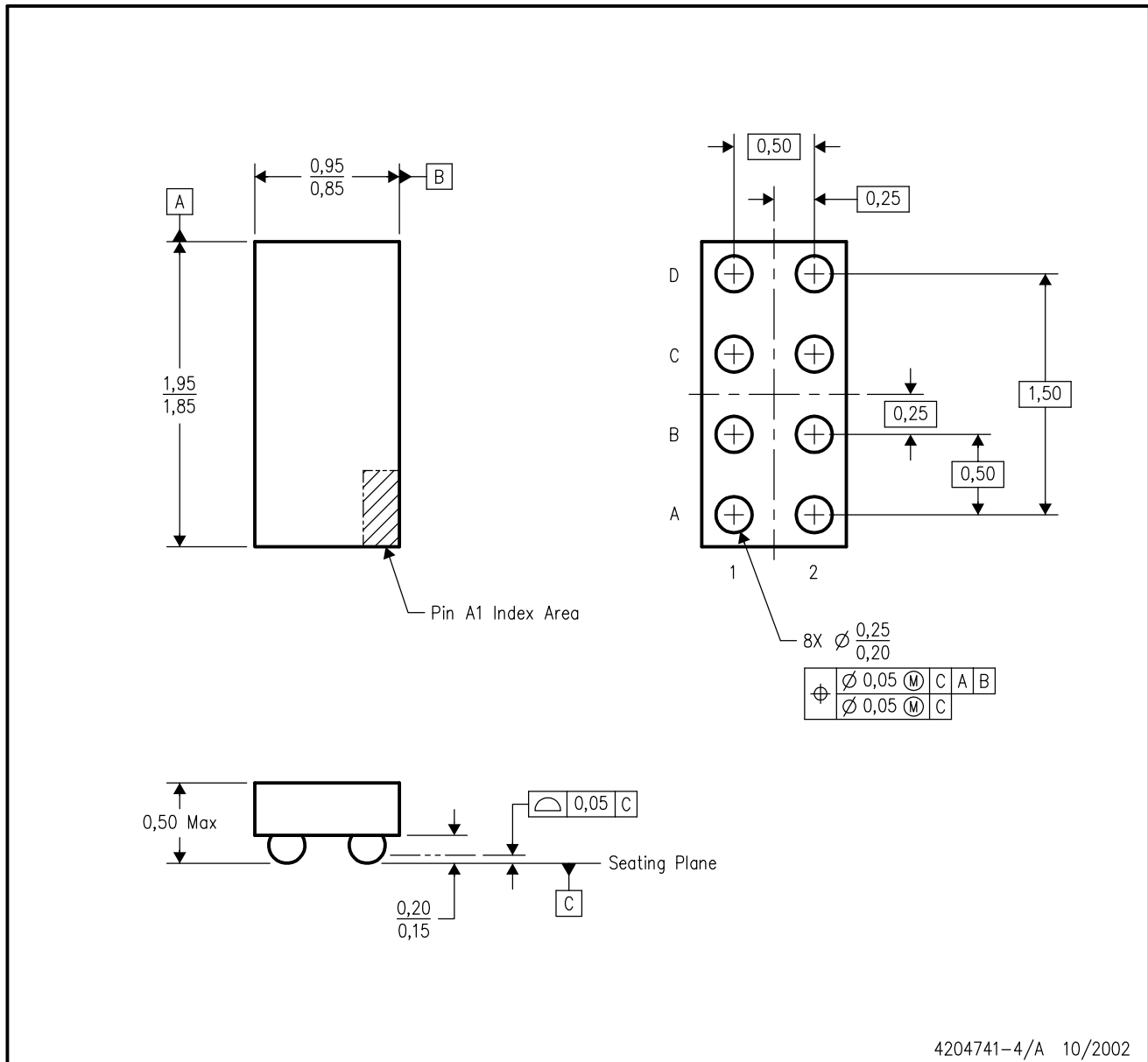


- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion.
  - Falls within JEDEC MO-187 variation CA.

## MECHANICAL DATA

YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY

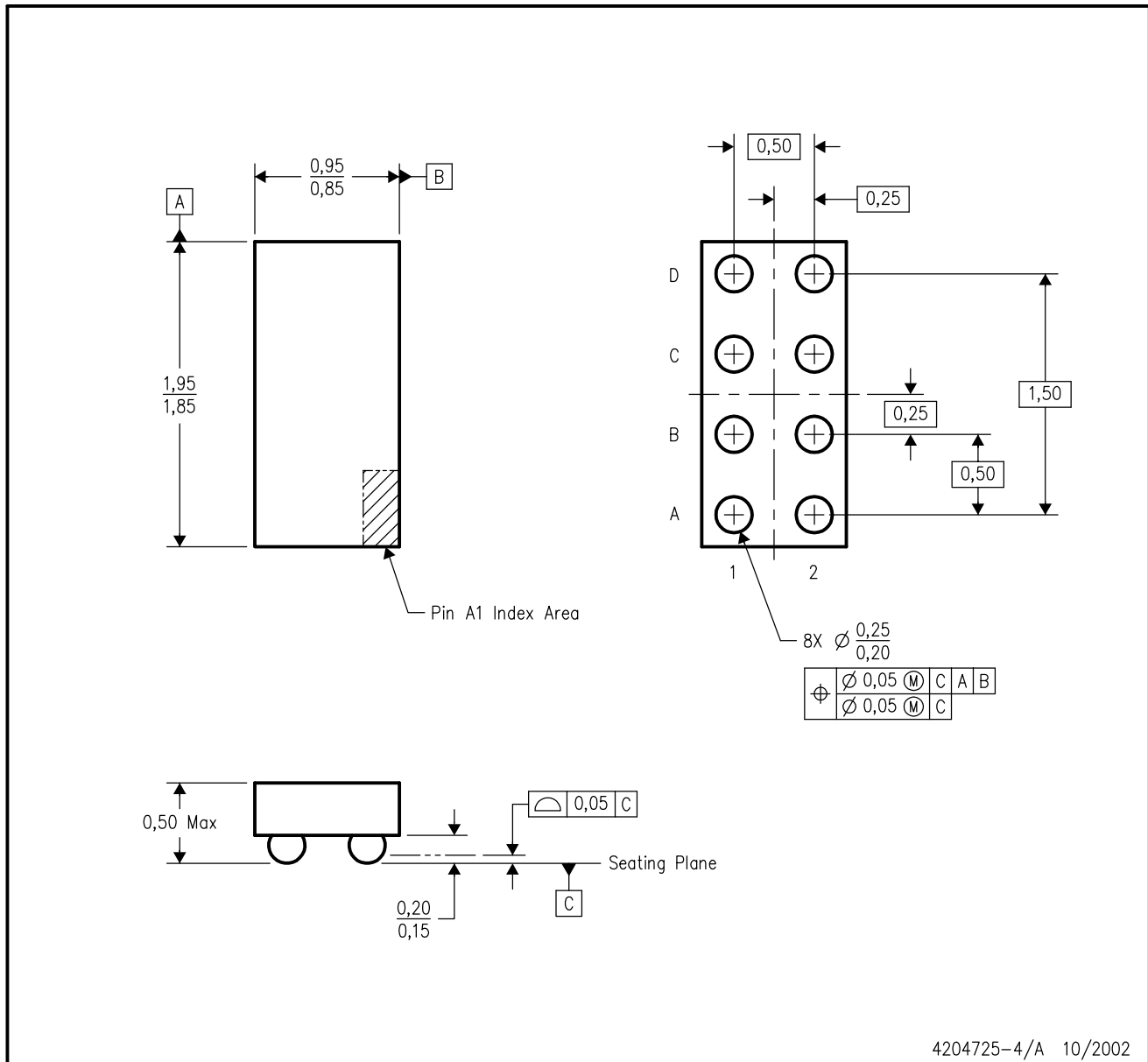


- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. NanoFree™ package configuration.
  - D. This package is lead-free. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

## MECHANICAL DATA

YEP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. NanoStar™ package configuration.
  - D. This package is tin-lead (SnPb). Refer to the 8 YZP package (drawing 4204741) for lead-free.

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